



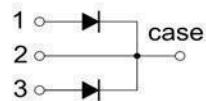
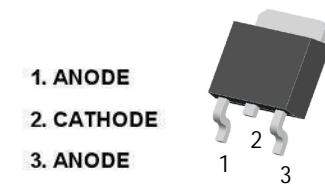
MBR10200

SCHOTTKY BARRIER RECTIFIER

TO-252

FEATURES

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	200	V
V_{RWM}	Working peak reverse voltage	140	V
$V_{R(RMS)}$	RMS reverse voltage	10	A
I_o	Average rectified output current	125	A
I_{FSM}	Non-repetitive peak forward surge current 8.3ms half sine wave	80	°C/W
P_D	Power dissipation	1.25	W
$R_{θJA}$	Thermal resistance from junction to ambient	125	°C
T_j	Junction temperature	-55~+150	°C
T_{stg}	Storage temperature		

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	200			V
Reverse current	I_R	$V_R=200\text{V}$			50	μA
Forward voltage	$V_{F(1)}$	$I_F=5\text{A}$		0.85	0.92	V
	$V_{F(2)}^*$	$I_F=10\text{A}$			1.1	V
Typical total capacitance	C_{tot}	$V_R=4\text{V}, f=1\text{MHz}$		50		pF

*Pulse test

